



TPH3208PS Information



For Reference Only

Part Number TPH3208PS **Manufacturer** Transphorm

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

Description GAN FET 650V 20A TO220

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









TPH3208PS Specifications

Manufacturer Part Number	TPH3208PS
Manufacturer	Transphorm
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	-
FET Type	N-Channel
Technology	GaNFET (Gallium Nitride)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	20A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	8V
Vgs(th) (Max) @ Id	2.6V @ 300μA
Gate Charge (Qg) (Max) @ Vgs	14nC @ 8V
Input Capacitance (Ciss) (Max) @ Vds	760pF @ 400V
Vgs (Max)	±18V
FET Feature	-
Power Dissipation (Max)	96W (Tc)
Rds On (Max) @ Id, Vgs	130 mOhm @ 13A, 8V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220
Package / Case	TO-220-3
	Report errors?

TPH3208PS Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

TPH3208PS Payment Methods



















TPH3208PS Shipping Methods













If you have any question about TPH3208PS, please do not hesitate to contact us!

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